

SURFACE MOUNT SWITCHING DIODE

Features

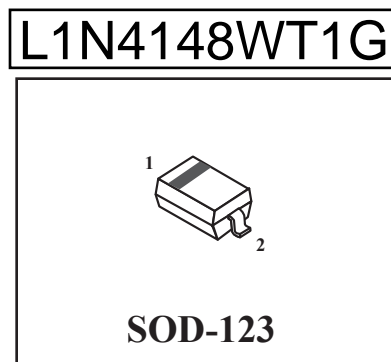
- Fast Switching Speed
- Surface Mount Package Ideally Suited for Automatic Insertion
- For General Purpose Switching Applications
- High Conductance
- Pb-Free package is available

Mechanical Data

- Case: SOD-123, Molded Plastic
- Terminals: Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Marking: Type Code only or Date Code and Type Code

Type Code: T4

- Weight: 0.01 grams (approx.)



Equivalent Circuit Diagram



Maximum Ratings @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	L1N4148WT1G	Unit
Non-Repetitive Peak Reverse Voltage	V _{RM}	100	V
Peak Repetitive Reverse Voltage	V _{RRM}	75	V
Working Peak Reverse Voltage	V _{RWM}		
DC Blocking Voltage	V _R		
RMS Reverse Voltage	V _{R(RMS)}	53	V
Forward Continuous Current (Note 1)	I _{FM}		
Average Rectified Output Current (Note 1)	I _O	150	mA
Non-Repetitive Peak Forward Surge Current @ t = 1.0μs @ t = 1.0s	I _{FSM}	2.0 1.0	A
Power Dissipation (Note 1)	P _d	350	mW
Thermal Resistance Junction to Ambient Air (Note 1)	R _{θJA}	357	K/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C

Electrical Characteristics @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
Maximum Forward Voltage	V _{FM}	—	0.715 0.855 1.0 1.25	V	I _F = 1.0mA I _F = 10mA I _F = 50mA I _F = 150mA
Maximum Peak Reverse Current	I _{RM}	—	2.5 50 30 25	μA μA nA	V _R = 75V V _R = 75V, T _J = 150°C V _R = 25V, T _J = 150°C V _R = 20V
Junction Capacitance	C _j	—	2.0	pF	V _R = 0, f = 1.0MHz
Reverse Recovery Time	t _{rr}	—	4.0	ns	I _F = I _R = 10mA, I _{rr} = 0.1 x I _R , R _L = 100Ω

Notes: 1. Valid provided that terminals are kept at ambient temperature.

L1N4148WT1G

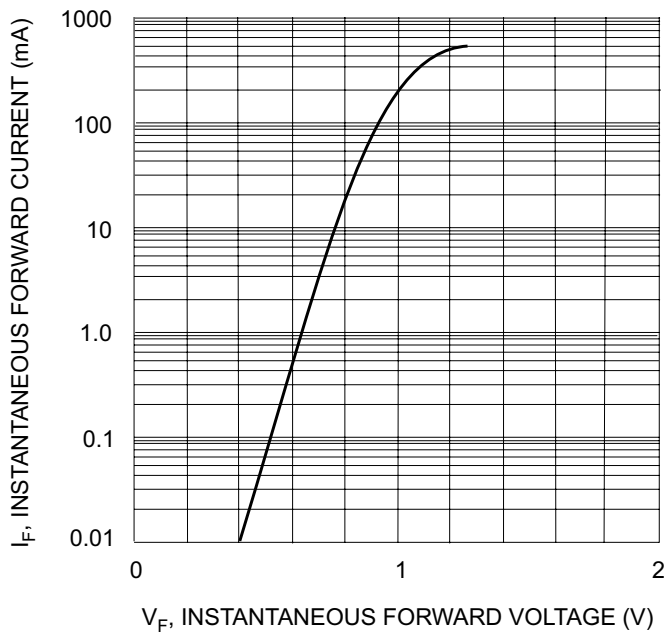


Fig. 1 Forward Characteristics

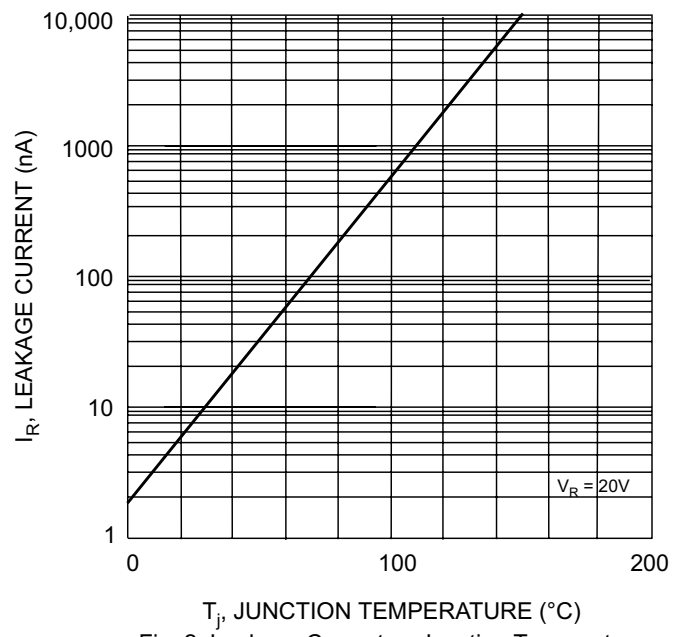


Fig. 2 Leakage Current vs Junction Temperature

SOD-123 Outline Dimensions

